BLS7G2729L-350P; BLS7G2729LS-350P LDMOS S-band radar power transistor Rev. 6 — 1 September 2015

AMPLEON

Product data sheet

Product profile

1.1 General description

350 W LDMOS power transistor for S-band radar applications in the frequency range from 2.7 GHz to 2.9 GHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25$ °C; $t_p = 300 \ \mu s$; $\delta = 10 \ \%$; $I_{Da} = 200 \ mA$; in a class-AB production test circuit.

Test signal	f	V _{DS}	PL	Gp	η_{D}	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	2.7 to 2.9	32	350	13	50	8	5

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for S-band operation (2.7 GHz to 2.9 GHz)
- Excellent thermal stability
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

S-band radar applications in the frequent range 2.7 GHz to 2.9 GHz

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLS7G27	29L-350P (SOT539A)			
1	drain1			
2	drain2		1 2	
3	gate1		5	
4	gate2		3 4	3 — 5
5	source	[1]		4
				<u>'</u>
				2 sym117
BLS7G27	29LS-350P (SOT539B)			
1	drain1			
2	drain2		1 2	1
3	gate1		5	
4	gate2		3 4	3 - 5
5	source	[1]		4 —
				' Ь
				2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	me Description \			
BLS7G2729L-350P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLS7G2729LS-350P	-	earless flanged balanced ceramic package; 4 leads	SOT539B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-0.5	+11	V
T _{stg}	storage temperature	- 65	+150	°C
Tj	junction temperature [1]	-	225	°C

Continuous use at maximum temperature will affect the reliability. For details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-mb)}}$	transient thermal impedance from junction	T _{case} = 85 °C; P _L = 350 W		
	to mounting base	t_p = 100 μ s; δ = 10 %	0.07	K/W
		t_p = 200 μ s; δ = 10 %	0.09	K/W
		t_p = 300 μ s; δ = 10 %	0.10	K/W
		t_p = 100 μ s; δ = 20 %	0.09	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.2 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 220 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	39	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 11.0 A	-	16.2	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 7.7 \text{ A}$	-	0.065	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 32 V; I_{Dq} = 200 mA; T_{case} = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 350 W	11	13	-	dB
RLin	input return loss	P _L = 350 W	-	-10	-	dB
η_{D}	drain efficiency	P _L = 350 W	46	50	-	%
P _{droop(pulse)}	pulse droop power	P _L = 350 W	-	0	0.5	dB
t _r	rise time	P _L = 350 W	-	8	50	ns
t _f	fall time	P _L = 350 W	-	5	50	ns

7. Test information

7.1 Ruggedness in class-AB operation

The BLS7G2729L-350P and BLS7G2729LS-350P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 200 mA; P_L = 350 W; t_p = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

f	Z _S [1]	Z _L [1]
GHz	Ω	Ω
2.7	2.8 – j8.7	1.8 – j5.1
2.8	3.9 – j8.2	2.1 – j5.4
2.9	4.8 – j9.3	1.5 – j5.7

[1] Impedances are taken at a single halve of the push-pull transistor

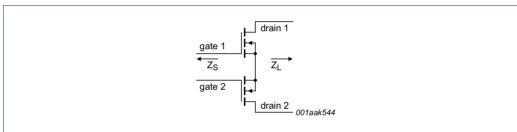
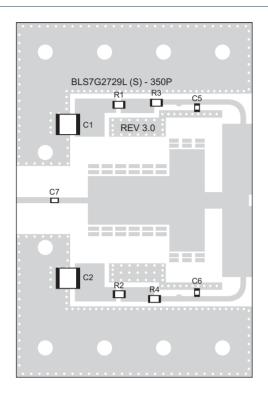
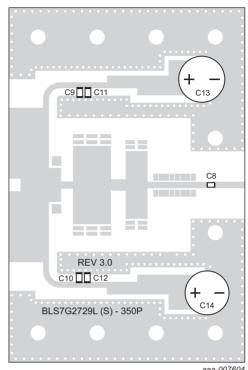


Fig 1. Definition of transistor impedance

7.3 Test circuit information





aaa-007604

Printed-Circuit Board (PCB): Rogers RO6006; ε_r = 6.45 F/m; thickness = 0.635 mm; thickness copper plating = 35 μ m. The vias can be used as a reference to place components.

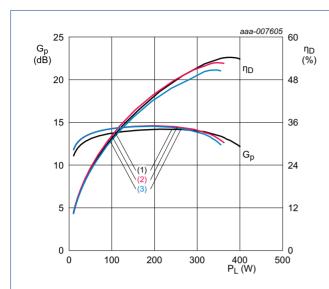
The above layout shows the test circuit used to measure the devices in production. A more appropriate application demonstration for specific customer needs can be provided. See Table 9 for list of components.

Fig 2. **Component layout**

List of components See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C2	SMD capacitor	4.7 μF, 50 V	
C5, C6	multilayer ceramic chip capacitor	12 pF	ATC800A
C7, C8	multilayer ceramic chip capacitor	20 pF	ATC800A
C9, C10	multilayer ceramic chip capacitor	12 pF	ATC800A
C11, C12	multilayer ceramic chip capacitor	1 nF	ATC700A
C13, C14	electrolytic capacitor	220 μF, 63 V	
R1, R2	SMD resistor	9.1 Ω	SMD 0805
R3, R4	SMD resistor	8 Ω	SMD 0805

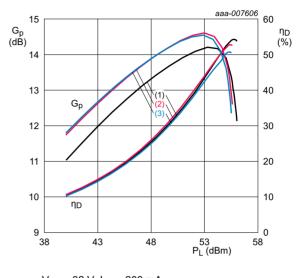
7.4 Graphical data



 $V_{DS} = 32 \text{ V}; I_{Dq} = 200 \text{ mA}.$

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz

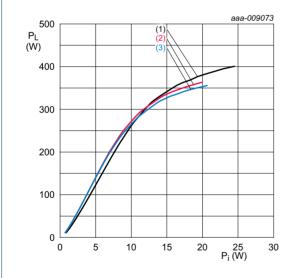
Fig 3. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA.

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz

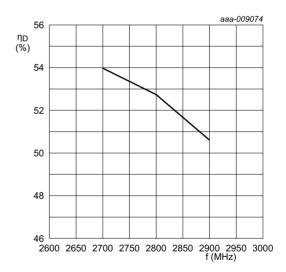
Fig 4. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; I_p =300 μ s; δ = 10 %.

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz

Fig 5. Output power as a function of input power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 300 $\mu s;$ δ = 10 %; P_L = 350 W.

Fig 6. Drain efficiency as a function of frequency; typical values

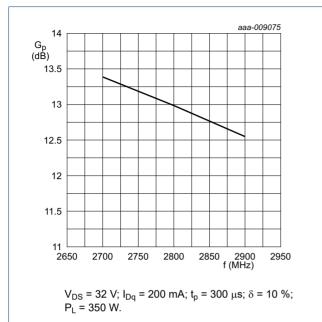


Fig 7. Power gain as a function of frequency; typical values

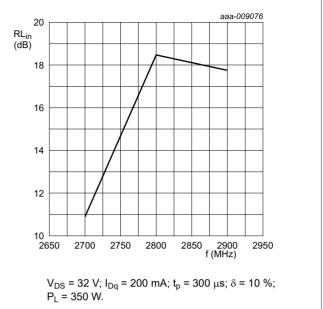
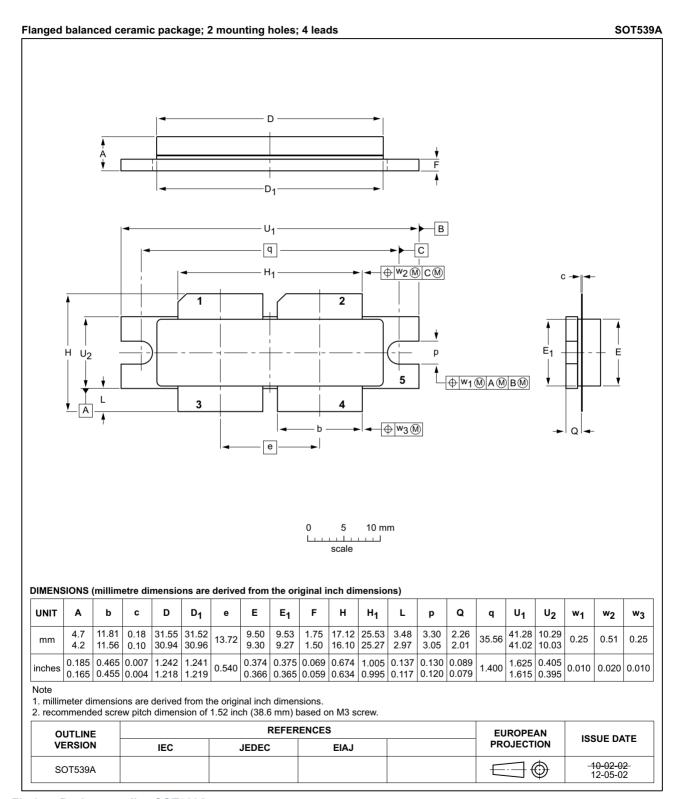


Fig 8. Input return loss as a function of frequency; typical values

Package outline 8.



Package outline SOT539A Fig 9.

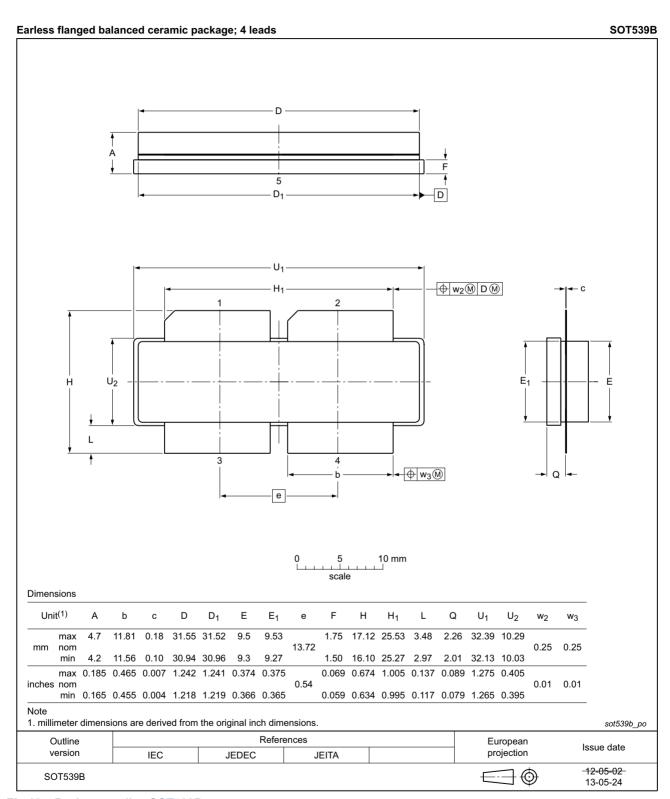


Fig 10. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description		
ESD	ElectroStatic Discharge		
LDMOS	aterally Diffused Metal-Oxide Semiconductor		
MTF	Median Time to Failure		
S-band	Short wave Band		
SMD	Surface-Mounted Device		
VSWR	Voltage Standing-Wave Ratio		

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS7G2729L-350P_LS-350P #6	20150901	Product data sheet		BLS7G2729L-350P_LS-350P v.5
Modifications:	guidelines	of Ampleon.		to comply with the new identity
	Legariexi	s nave been adapted to	o the new compa	пу паше мпете арргорпате.
BLS7G2729L-350P_LS-350P v.5	20140516	Product data sheet	-	BLS7G2729L-350P_LS-350P v.4
BLS7G2729L-350P_LS-350P v.4	20130923	Product data sheet	-	BLS7G2729L-350P_LS-350P v.3
BLS7G2729L-350P_LS-350P v.3	20130712	Objective data sheet	-	BLS7G2729L-350P_LS-350P v.2
BLS7G2729L-350P_LS-350P v.2	20130506	Objective data sheet	-	BLS7G2729L-350P_LS-350P v.1
BLS7G2729L-350P_LS-350P v.1	20110524	Objective data sheet	-	-

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Document status[1][2]	Product status[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

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LDMOS S-band radar power transistor

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